160V NPN HIGH VOLTAGE TRANSISTOR IN SOT223

Features

- BV_{CEO} > 160V
- BV_{EBO} > 6V
- I_C = 600mA Continuous Collector Current
- Low Saturation Voltage (150mV max @10mA)
- h_{FE} specified up to 50mA for a high gain hold up
- Complementary PNP Type: DZT5401
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/**

Mechanical Data

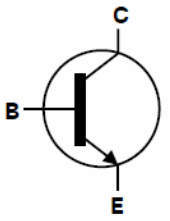
- Package: SOT223
- Package material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.112 grams (approximate)

Applications

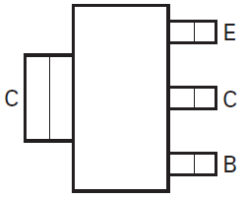
- High-voltage amplification applications
- High-voltage switching applications

SOT223

Top View



Device Schematic



Pin-Out Top View

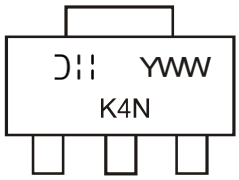
Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (Inches)	Tape Width (mm)	Packing	
					Quantity	Carrier
DZT5551-13	SOT223	K4N	13	12	2,500	Reel

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

(Top View)



K4N = Product type marking code
= Manufacturer's code marking
YWW = Date code marking
Y = Last digit of year ex: 7 = 2007
WW = Week code 01 - 52

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	180	V
Collector-Emitter Voltage	V_{CEO}	160	V
Emitter-Base Voltage	V_{EBO}	6	V
Continuous Collector Current	I_C	600	mA
Peak Collector Current	I_{CM}	1	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_D	2	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	62.5	°C/W
Thermal Resistance, Junction to Leads (Note 6)	$R_{\theta JL}$	45	°C/W
Thermal Resistance, Junction to Case (Note 7)	$R_{\theta JC}$	27	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Notes: 5. Device mounted on 50mm X 50mm X 1.6mm FR-4 PCB with high coverage of single sided 1 oz. copper, in still air condition
6. Thermal resistance from junction to solder-point (at the end of the collector lead).
7. Thermal resistance from junction to the top of the case.

Thermal Characteristics and Derating Information

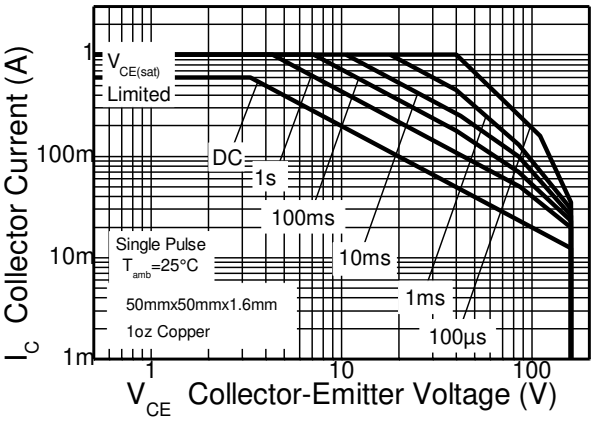


Figure 1. Safe Operating Area

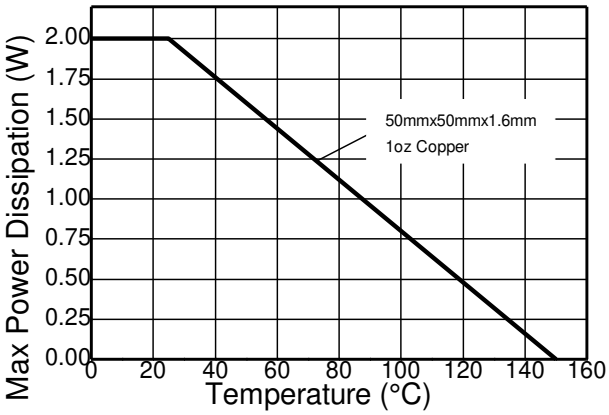


Figure 2. Derating Curve

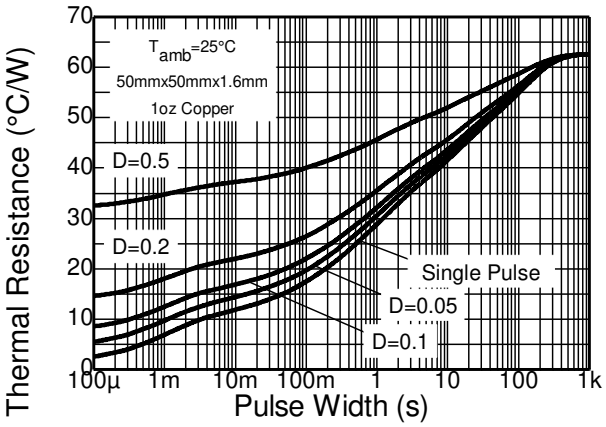


Figure 3. Transient Thermal Impedance

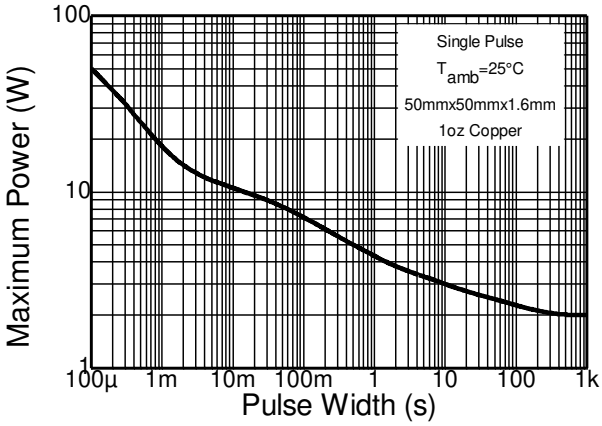


Figure 4. Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV_{CBO}	180	270	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage (Note 8)	BV_{CEO}	160	200	—	V	I_C = 1mA
Emitter-Base Breakdown Voltage	BV_{EBO}	6.0	7.85	—	V	I_E = 100µA
Collector Cutoff Current	I_{CBO}	— —	1 —	50 50	nA µA	V_{CB} = 120V V_{CB} = 120V, T_A = +100°C
Emitter Cutoff Current	I_{EBO}	—	1	50	nA	V_{EB} = 4V
ON CHARACTERISTICS (Note 8)						
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	— —	65 115	150 200	mV mV	I_C = 10mA, I_B = 1mA I_C = 50mA, I_B = 5mA
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	— —	760 840	1000 1200	mV mV	I_C = 10mA, I_B = 1mA I_C = 50mA, I_B = 5mA
DC Current Gain	h_{FE}	80 80 30	130 145 65	— 250 —	—	I_C = 1mA, V_{CE} = 5V I_C = 10mA, V_{CE} = 5V I_C = 50mA, V_{CE} = 5V
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f_T	100	130	300	MHz	V_{CE} = 10V, I_C = 10mA, f = 100MHz
Small Signal Current Gain	h_{fe}	50	—	260	—	V_{CE} = 10V, I_C = 10mA, f = 1kHz
Output Capacitance	C_{obo}	—	—	6	pF	V_{CB} = 10V, f = 1MHz
Noise Figure	NF	—	—	8	dB	V_{CE} = 5.0V, I_C = 200µA, R_S = 1.0kΩ, f = 1.0kHz
Delay Time	$t_{(d)}$	—	95	—	ns	V_{CC} = 10V, I_C = 10mA, I_{B1} = -I_{B2} = 1mA
Rise Time	$t_{(r)}$	—	64	—	ns	
Storage Time	$t_{(s)}$	—	1256	—	ns	
Delay Time	$t_{(f)}$	—	140	—	ns	

Notes: 8. Pulse Test: Pulse width ≤ 300µs. Duty cycle ≤ 2.0%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

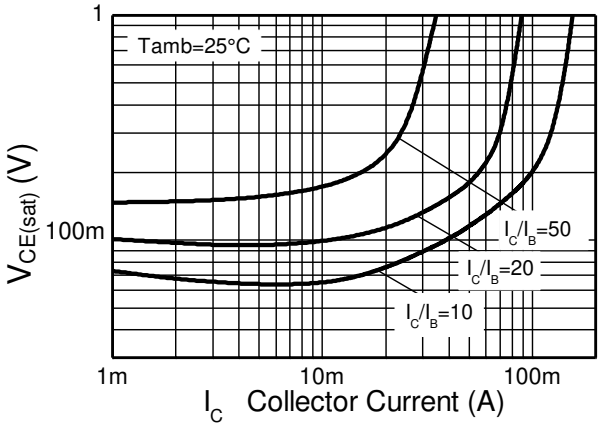


Figure 5. $V_{CE(sat)}$ v I_C

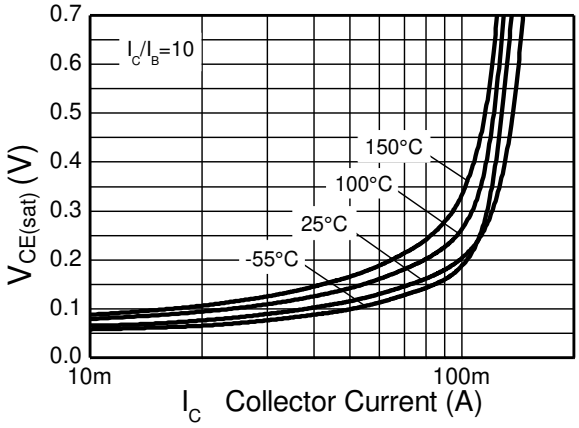


Figure 6. $V_{CE(sat)}$ v I_C

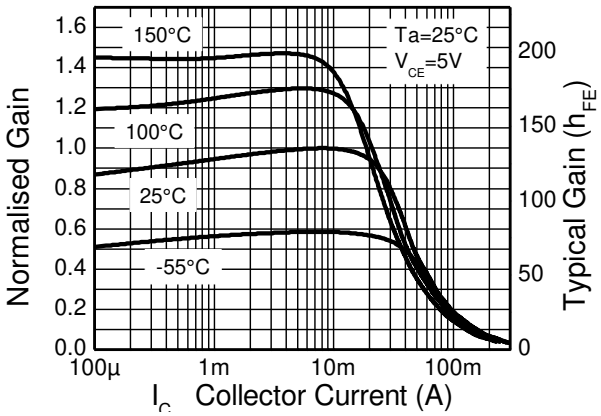


Figure 7. h_{FE} v I_C

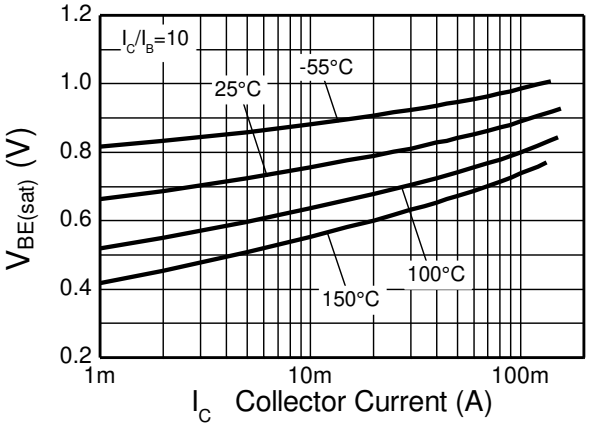


Figure 8. $V_{BE(sat)}$ v I_C

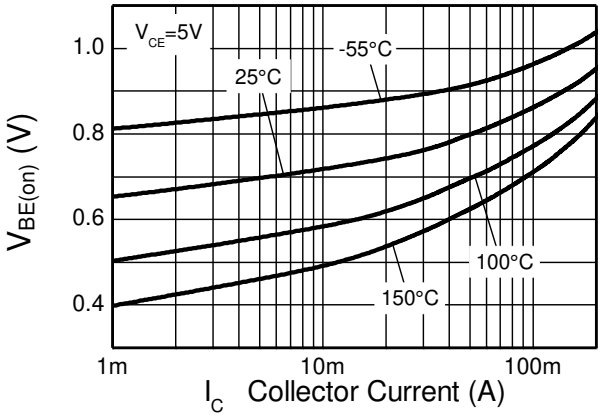


Figure 9. $V_{BE(on)}$ v I_C

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

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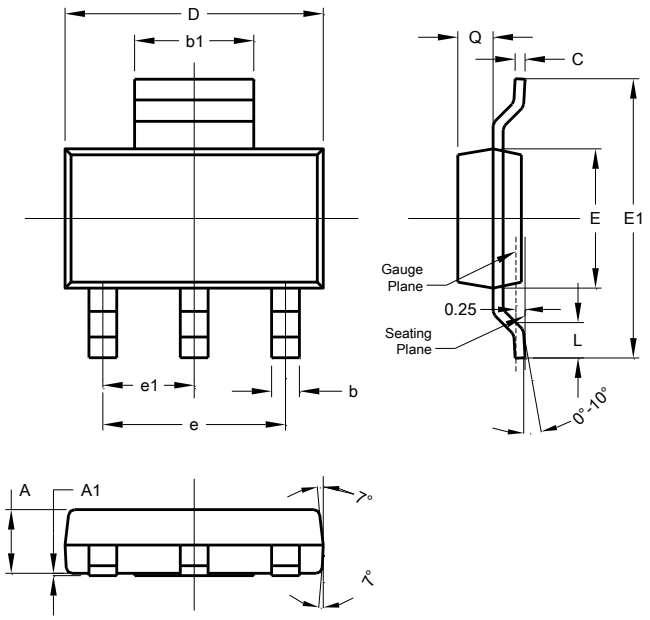
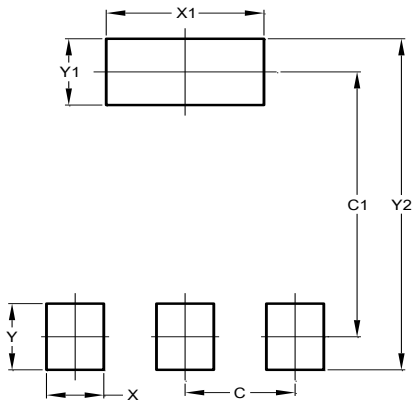


SOT223			
Dim	**Min**	**Max**	**Typ**
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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